# **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

ON Semiconductor NJD35N04G

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>



# NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

# **NPN Darlington Power Transistor**

This high voltage power Darlington has been specifically designed for inductive applications such as Electronic Ignition, Switching Regulators and Motor Control.

#### **Features**

- Exceptional Safe Operating Area
- High V<sub>CE</sub>; High Current Gain
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices\*

#### Benefits

- Reliable Performance at Higher Powers
- Designed for Inductive Loads
- Very Low Current Requirements

#### **Applications**

- Internal Combustion Engine Ignition Control
- Switching Regulators
- Motor Controls
- Light Ballast
- Photo Flash

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Sustaining Voltage	V <sub>CEO</sub>	350	Vdc
Collector-Base Breakdown Voltage	V <sub>CBO</sub>	700	Vdc
Collector-Emitter Breakdown Voltage	V <sub>CES</sub>	700	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current Continuous Peak	I <sub>C</sub>	4.0 8.0	Adc
Base Current	I <sub>B</sub>	0.5	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	45 0.36	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



### ON Semiconductor®

http://onsemi.com

# DARLINGTON POWER TRANSISTORS 4 AMPERES 350 VOLTS 45 WATTS



DPAK CASE 369C STYLE 1

#### MARKING DIAGRAM



Y = Year

WW = Work Week

NJD35N04 = Device Code

G = Pb-Free Device

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJVNJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJD35N04T4G	DPAK (Pb-Free)	2,500 / Tape & Reel
NJVNJD35N04T4G	DPAK (Pb-Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient	${\sf R}_{ heta {\sf JC}} \ {\sf R}_{ heta {\sf JA}}$	2.78 71.4	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	1				
Collector-Emitter Sustaining Voltage (I <sub>C</sub> = 10 mA, L = 10 mH)	V <sub>CEO(sus)</sub>	350	-	-	V
Collector Cutoff Current ( $V_{CE}$ = 500 V) ( $I_{B}$ = 0) ( $V_{CE}$ = 500 V, $T_{C}$ = 125°C)	I <sub>CES</sub>	1 1		50 250	μΑ
Collector Cutoff Current ( $V_{CE}$ = 250 V) ( $I_{B}$ = 0) ( $V_{CE}$ = 200 V, $T_{C}$ = 125°C)	I <sub>CEO</sub>	- -	- -	50 250	μΑ
Emitter Cutoff Current (V <sub>BE</sub> = 5.0 Vdc)	I <sub>EBO</sub>	-	-	5.0	μΑ
ON CHARACTERISTICS	1		1	1	
Collector–Emitter Saturation Voltage ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA}$ ) ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA}$ 125°C)	V <sub>CE(sat)</sub>	- -	- -	1.5 1.5	V
Base–Emitter Saturation Voltage ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA}$ ) ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA}$ 125°C)	V <sub>BE(sat)</sub>	- -	- -	2.0 2.0	V
Base–Emitter On Voltage $(I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V})$ $(I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V}] 25^{\circ}\text{C})$	V <sub>BE(on)</sub>	- -	- -	2.0 2.0	٧
DC Current Gain $(I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V})$ $(I_C = 4.0 \text{ A}, V_{CE} = 2.0 \text{ Vdc})$	h <sub>FE</sub>	2000 300	_ _	_ _	-
DYNAMIC CHARACTERISTICS	<u> </u>				!
Current-Gain - Bandwidth Product (I <sub>C</sub> = 2.0 A, V <sub>CE</sub> = 10 V, f = 1.0 MHz)	f <sub>T</sub>	90	-	_	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 0.1 MHz)	C <sub>ob</sub>	-	60	-	pF
SWITCHING CHARACTERISTICS	1		1	1	
$V_{CC}$ = 12 V, $V_{clamp}$ = 250 V, L = 4 mH $I_{C}$ = 2 A, $I_{B1}$ = 20 mA, $I_{B2}$ = -20 mA	t <sub>s</sub>	- -	18 0.8	_ _	μSec

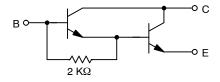
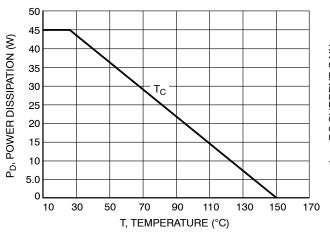


Figure 1. Darlington Circuit Schematic



## NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

#### **TYPICAL CHARACTERISTICS**



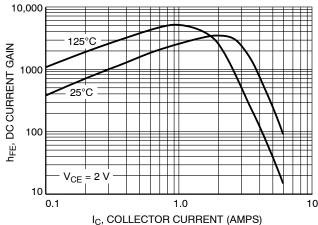
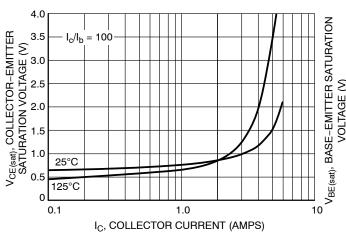


Figure 2. Power Derating

Figure 3. DC Current Gain



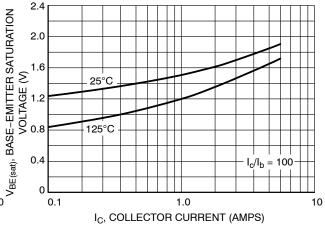
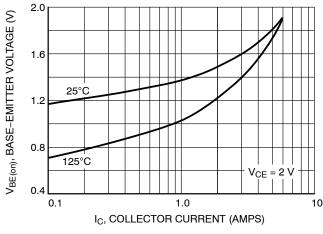


Figure 4. Collector-Emitter Saturation Voltage

Figure 5. Base-Emitter Saturation Voltage



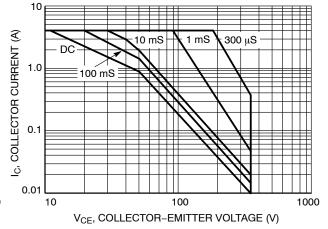


Figure 6. Base-Emitter Voltage

Figure 7. Forward Bias Safe Operating Area (FBSOA)



## Distributor of ON Semiconductor: Excellent Integrated System Limited

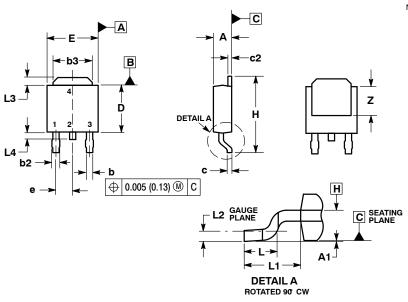
Datasheet of NJD35N04G - TRANS NPN DARL 350V 4A DPAK

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

#### NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

#### PACKAGE DIMENSIONS

#### DPAK CASE 369C-01 ISSUE D



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCHES.

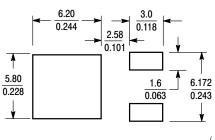
- CONTROLLING DIMENSION: INCHES.
   THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
   DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
   DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
   DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

_					
	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
A1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
E	0.250	0.265	6.35	6.73	
е	0.090 BSC		2.29 BSC		
Н	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74 REF		
L2	0.020 BSC		0.51 BSC		
L3	0.035	0.050	0.89	1.27	
L4		0.040		1.01	
Z	0 155		3 93		

STYLE 1

PIN 1. BASE 2. COLLECTOR EMITTER COLLECTOR

#### **SOLDERING FOOTPRINT\***



SCALE 3:1

ON Semiconductor and a registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. An operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application, which the failure of the SCILLC products could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death of the products of the performance of the performance for the performance of the performance for the performance of the performance for the performance for the performance of the performance of the performance of the performance for the performance of associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.